



GaAs MMIC I/Q MIXER 4 - 8.5 GHz

Typical Applications

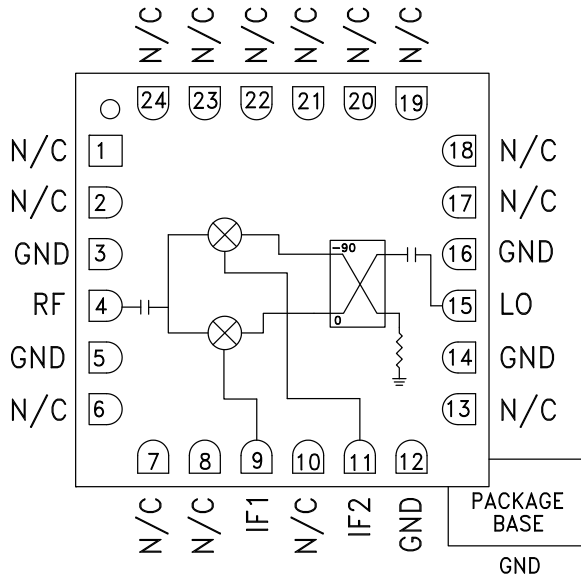
The HMC525LC4 is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- VSAT

Features

- Wide IF Bandwidth: DC - 3.5 GHz
- Image Rejection: 40 dB
- LO to RF Isolation: 50 dB
- High Input IP3: +23 dBm
- 24 Lead 4x4mm SMT Package: 16mm²

Functional Diagram



General Description

The HMC525LC4 is a compact I/Q MMIC mixer in a leadless "Pb free" RoHS compliant SMT package, which can be used as either an Image Reject Mixer or a Single Sideband Upconverter. The mixer utilizes two standard Hittite double balanced mixer cells and a 90 degree hybrid fabricated in a GaAs MESFET process. A low frequency quadrature hybrid was used to produce a 100 MHz USB IF output. This product is a much smaller alternative to hybrid style Image Reject Mixers and Single Sideband Upconverter assemblies. The HMC525LC4 eliminates the need for wire bonding allowing use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25\text{ }^\circ\text{C}$, $IF = 100\text{ MHz}$, $LO = +15\text{ dBm}$ *

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, RF/LO	4.0 - 8.5			5.5 - 7.5			GHz
Frequency Range, IF	DC - 3.5			DC - 3.5			GHz
Conversion Loss (As IRM)		8	11		7.5	9.5	dB
Image Rejection	20	35		30	40		dB
1 dB Compression (Input)		+14			+15		dBm
LO to RF Isolation	33	45		40	50		dB
LO to IF Isolation	14	20		17	20		dB
IP3 (Input)		+23			+23		dBm
Amplitude Balance		0.3			0.2		dB
Phase Balance		8			4		Deg

* Unless otherwise noted, all measurements performed as downconverter.

HMC525* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- HMC525LC4 Evaluation Board.

DOCUMENTATION

Data Sheet

- HMC525 Die Data Sheet
- HMC525LC4 Data Sheet

TOOLS AND SIMULATIONS

- HMC525 S-Parameters

REFERENCE MATERIALS

Quality Documentation

- Package/Assembly Qualification Test Report: LC4, LC4B (QTR: 2014-00380 REV: 01)
- Semiconductor Qualification Test Report: MESFET-B (QTR: 2013-00245)

DESIGN RESOURCES

- HMC525 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC525 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.



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4 - 8.5 GHz**

Data taken As IRM With External IF Hybrid

Conversion Gain vs. Temperature

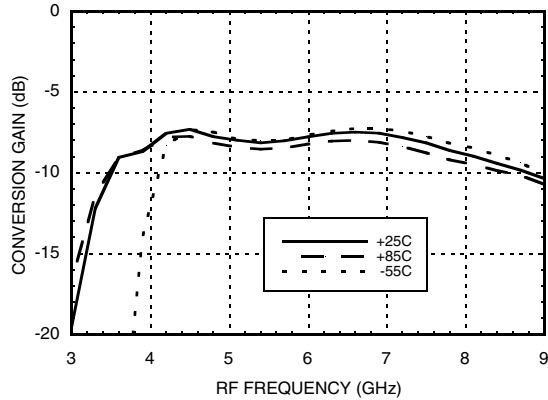
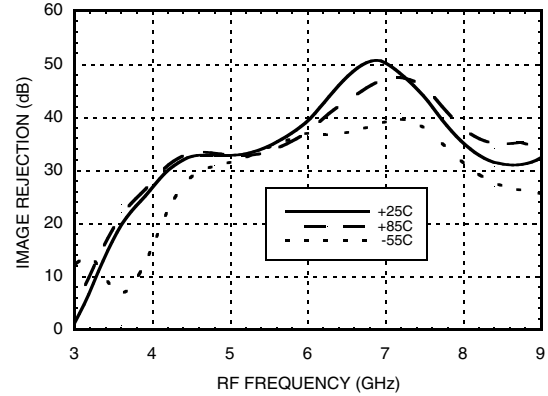
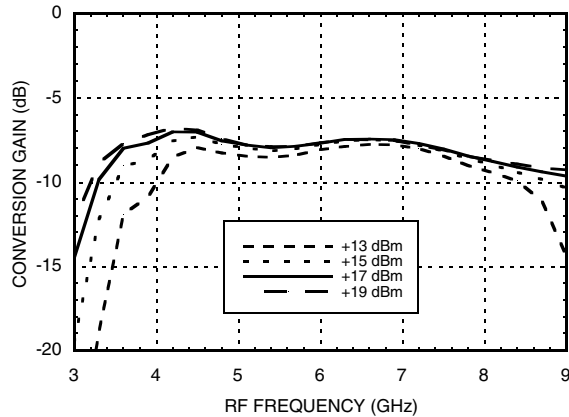


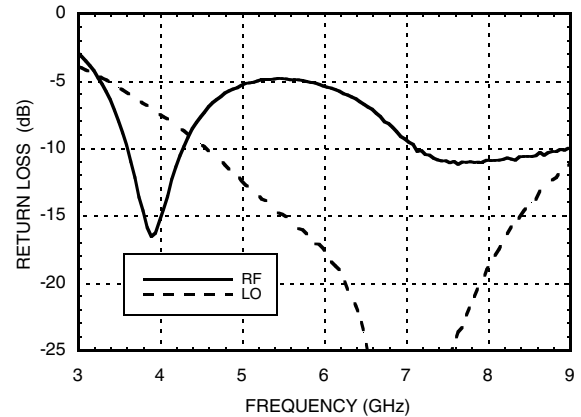
Image Rejection vs. Temperature



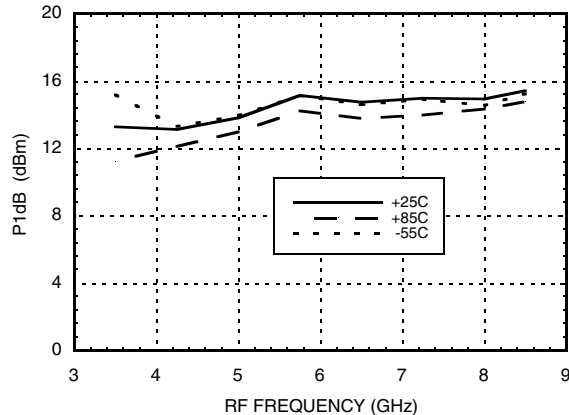
Conversion Gain vs. LO Drive



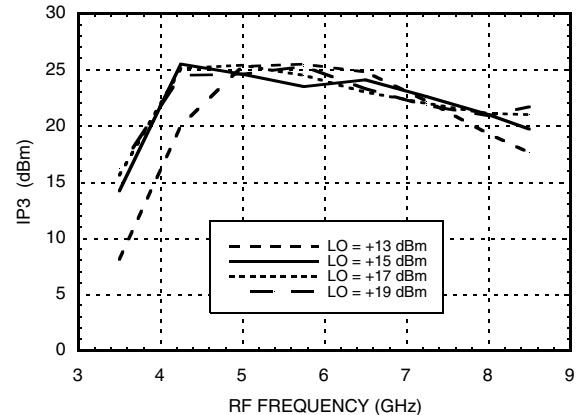
Return Loss



Input P1dB vs. Temperature



Input IP3 vs. LO Drive



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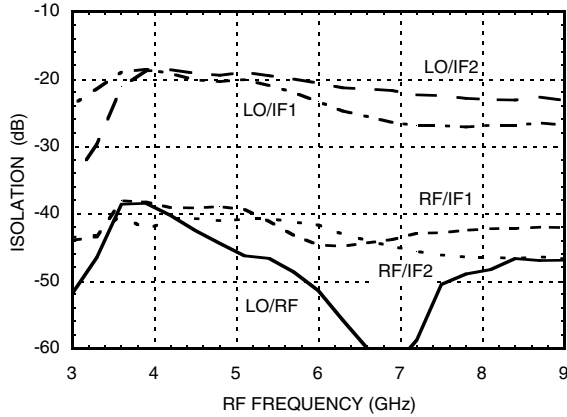
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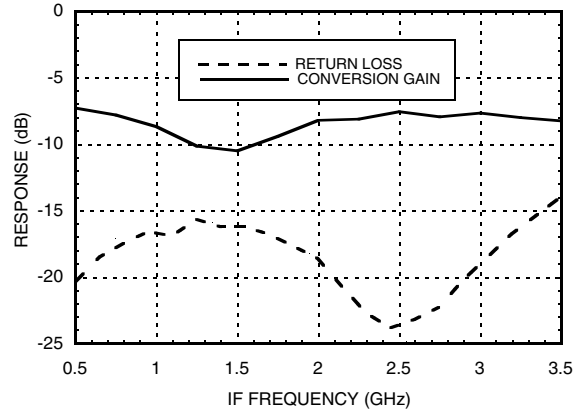
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Quadrature Channel Data Taken Without IF Hybrid

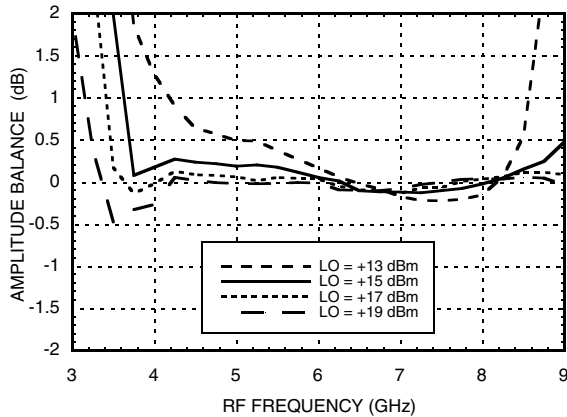
Isolations



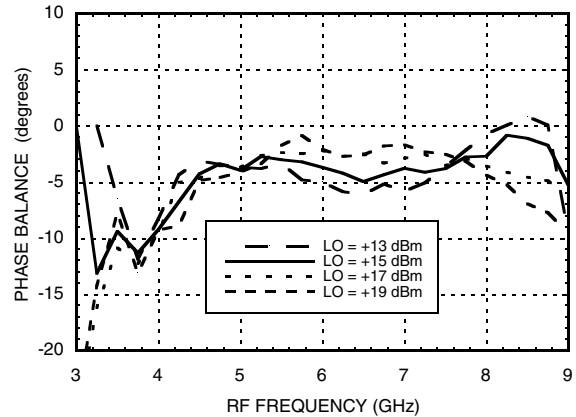
IF Bandwidth*



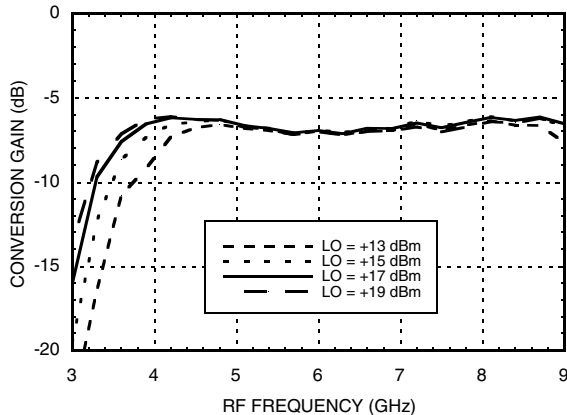
Amplitude Balance vs. LO Drive



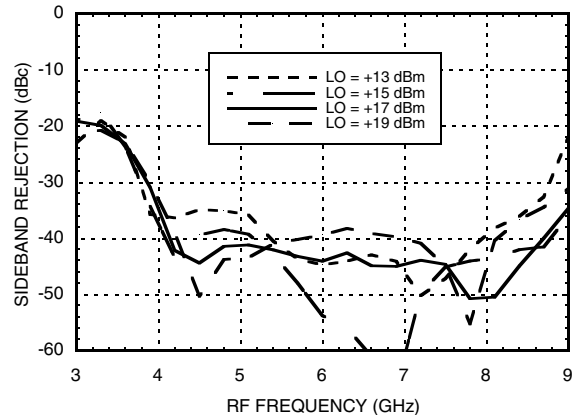
Phase Balance vs. LO Drive



Upconverter Performance Conversion Gain vs. LO Drive



Upconverter Performance Sideband Rejection vs. LO Drive



* Conversion gain data taken with external IF hybrid

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Harmonics of LO

LO Freq. (GHz)	nLO Spur at RF Port			
	1	2	3	4
3.5	40	40	54	50
4.5	43	45	58	53
5.5	51	57	48	67
6.5	59	63	64	56
7.5	48	66	64	62
8.5	44	65	60	67

LO = +15 dBm
Values in dBc below input LO level measured at RF Port.

MxN Spurious Outputs

mRF	nLO				
	0	1	2	3	4
0	xx	-11	32	23	51
1	32	0	42	51	66
2	89	62	74	65	89
3	89	89	89	82	89
4	89	89	89	89	89

RF = 5.6 GHz @ -10 dBm
LO = 5.5 GHz @ +15 dBm
Data taken without IF hybrid
All values in dBc below IF power level

Absolute Maximum Ratings

RF / IF Input	+20 dBm
LO Drive	+27 dBm
Channel Temperature	150°C
Continuous Pdiss (T=85°C) (derate 9.7 mW/°C above 85°C)	631 mW
Thermal Resistance (R _{TH}) (junction to die bottom)	103 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C

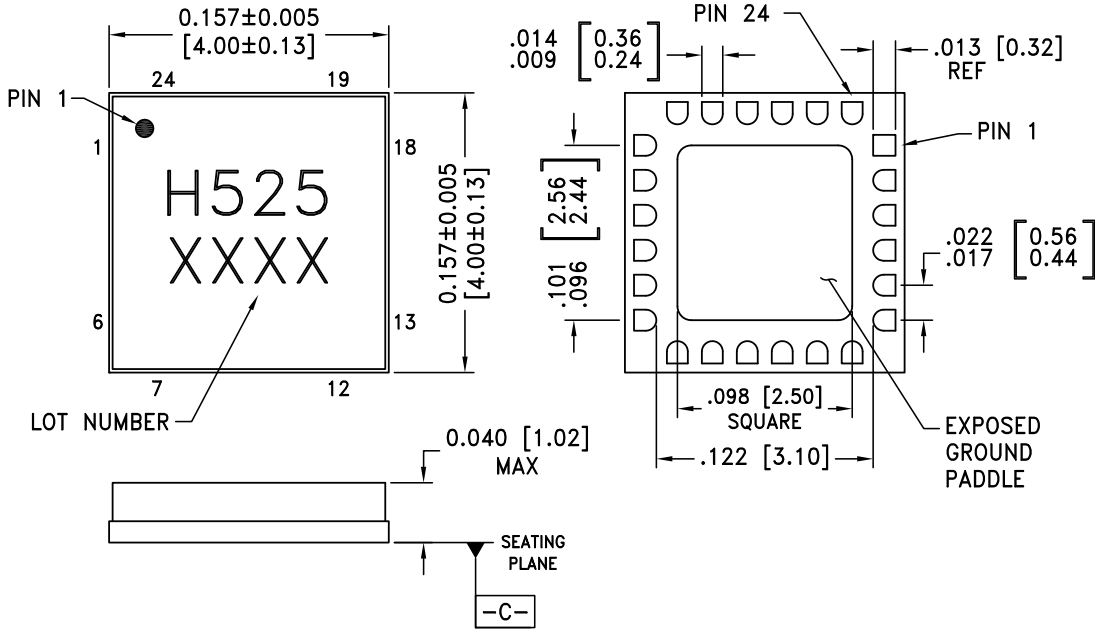


ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS



Outline Drawing

BOTTOM VIEW



NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING: 30 - 80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKLE
3. DIMENSIONS ARE IN INCHES [MILLIMETERS]
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC525LC4	Alumina, White	Gold over Nickel	MSL3 ^[1]	H525 XXXX


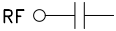
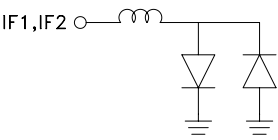
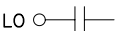
[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX



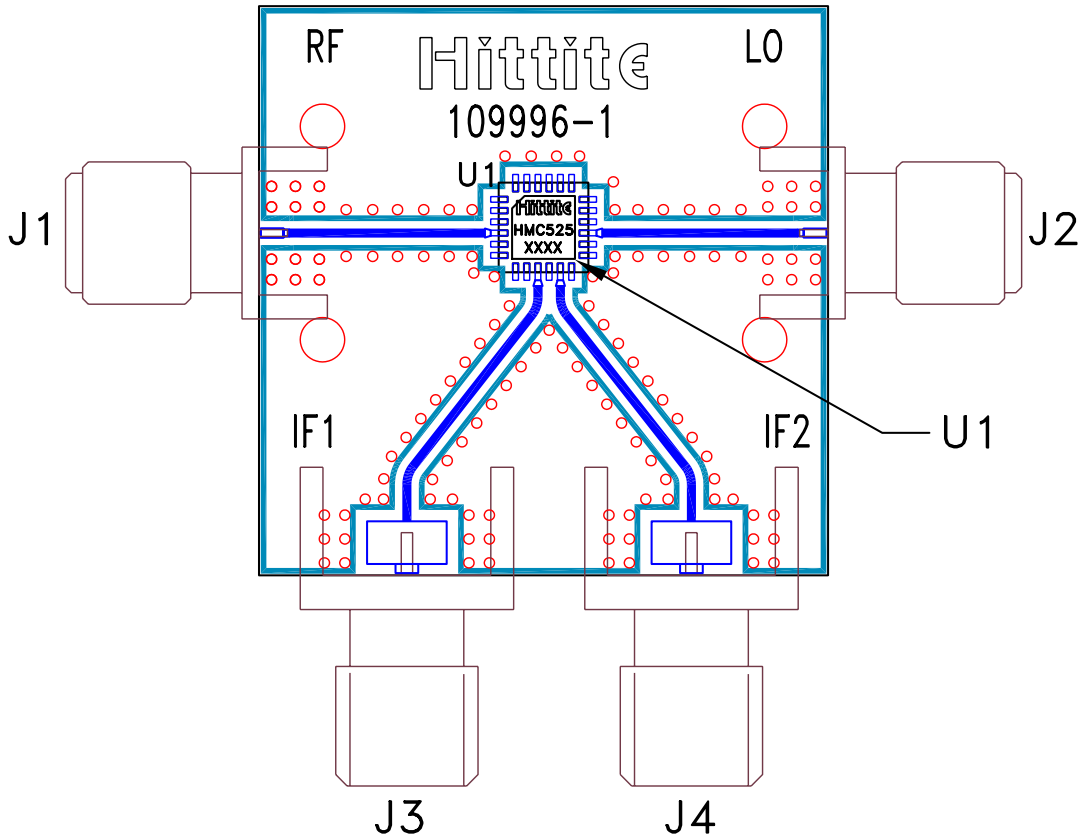
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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 6 - 8, 10, 13, 17 - 24	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	
3, 5, 12, 14, 16	GND	These pins and package bottom must be connected to RF/DC ground.	
4	RF	This pin is AC coupled and matched to 50 Ohms from 4 to 8.5 GHz.	
9	IF1	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source/sink more than 3mA of current or part non-function and possible part failure will result.	
11	IF2		
15	LO	This pin is AC coupled and matched to 50 Ohms from 4 to 8.5 GHz.	



Evaluation PCB



List of Materials for Evaluation PCB 109998^[1]

Item	Description
J1, J2	PCB Mount SMA RF Connector, SRI
J3 - J4	PCB Mount SMA Connector, Johnson
U1	HMC525LC4
PCB [2]	109996 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

